MOSEL

MS62256A

## 32K x 8 High Speed CMOS Static RAM

FEATURES

- High-speed – 25/30/35/45/55 ns
- Low Power dissipation:

  MS62256AL

    990mW (Max.) Operating

    550µW (Max.) Power Down

    50µA (Max.) I_{CCDR}

- Fully static operation
- All inputs and outputs directly TTL compatible
- Three state outputs
- Ultra low data retention supply current at V_{CC} = 2V
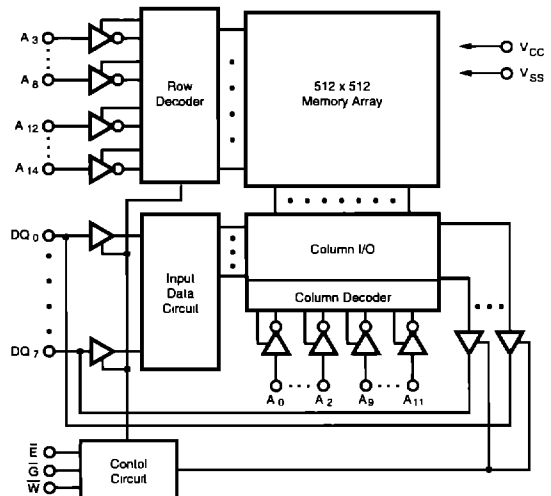
DESCRIPTION

The MOSEL MS62256A is a 262,144-bit static random access memory organized as 32,768 words by 8 bits and operates from a single 5 volt supply. It is built with MOSEL's high performance twin tub CMOS process. Inputs and three-state outputs are TTL compatible and allow for direct interfacing with common system bus structures. The MS62256A is available in the following standard 28-pin packages:

    600 MIL Plastic DIP
    300 MIL Plastic DIP
    300 MIL Small Outline J-Bend (SOJ)
    300 MIL Small Outline Gullwing (SOG)

PIN CONFIGURATIONS
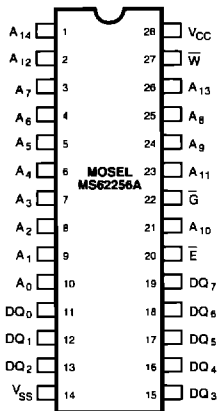
FUNCTIONAL BLOCK DIAGRAM

PIN DESCRIPTIONS

A_0 - A_{14} Address Inputs

These 15 address inputs select one of the 32768 8-bit words in the RAM

$\overline{E}$ Chip Enable Input

$\overline{E}$ is active LOW The chip enable must be active to read from or write to the device If it is not active, the device is deselected and is in a standby power mode. The DQ pins will be in the high-impedance state when deselected.

$\overline{G}$ Output Enable Input

The output enable input is active LOW. If the output enable is active while the chip is selected and the write enable is inactive, data will be present on the DQ pins and they will be enabled. The DQ pins will be in the high impedance state when $\overline{G}$ is inactive.

$\overline{W}$ Write Enable Input

The write enable input is active LOW and controls read and write operations. With the chip enabled, when $\overline{W}$ is HIGH and $\overline{G}$ is LOW, output data will be present at the DQ pins; when $\overline{W}$ is LOW, the data present on the DQ pins will be written into the selected memory location.

DQ_0 - DQ_7 Data Input/Output Ports

These 8 bidirectional ports are used to read data from or write data into the RAM

V_{cc} Power Supply

Vss   Ground

TRUTH TABLE

MODE	$\overline{E}$	$\overline{G}$	$\overline{W}$	I/O OPERATION
Standby	H	X	X	High Z
Read	L	L	H	D_{OUT}
Read	L	H	H	High Z
Write	L	X	L	D_{IN}

OPERATING RANGE

RANGE	AMBIENT TEMPERATURE	V_{CC}
Commercial	0°C to +70°C	5V ± 10%

ABSOLUTE MAXIMUM RATINGS [1]

SYMBOL	PARAMETER		RATING	UNITS
V_{CC}	Supply Voltage		-0.3 to 7	V
V_{IN}	Input Voltage		-0.3 to 7	
V_{DQ}	Input/Output Voltage Applied		-0 3 to 6	
T_{BIAS}	Temperature Under Bias	Plastic	-10 to +125	°C
T_{STG}	Storage Temperature	Plastic	-40 to +150	°C
P_D	Power Dissipation		1.0	W
I_{OUT}	DC Output Current		50	mA

1 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability and degrade performance characteristics.

MS62256A

DC ELECTRICAL CHARACTERISTICS (over the commercial operating range)

PARAMETER NAME	PARAMETER	TEST CONDITIONS	MS62256A MIN.	TYP. [1]	MAX.	UNITS
V_{IL}	Guaranteed Input Low Voltage[2,3]		−0 3	-	0 8	V
V_{IH}	Guaranteed Input High Voltage[2]		2 2	-	6 0	V
I_{IL}	Input Leakage Current	V_{CC} = Max, V_{IN} = 0V to V_{CC}	-	-	2	μA
I_{OL}	Output Leakage Current	V_{CC} = Max, $\overline{E}$ = V_{IH}, or $\overline{G}$ = V_{IH}, V_{IN} = 0V t o V_{CC}	-	-	2	μA
V_{OL}	Output Low Voltage	V_{CC} = Min, I_{OL} = 4mA	-	-	0 4	V
V_{OH}	Output High Voltage	V_{CC} = Min, I_{OH} = −1 0mA	2 4	-	-	V
I_{CC}	Operating Power Supply Current	V_{CC} = Max, $\overline{E}$ = V_{IL}, I_{DQ} = 0mA, F = F_{max}[4]	-	-	180	mA
I_{CCSB}	Standby Power Supply Current	V_{CC} = Max, $\overline{E}$ = V_{IH}, I_{DQ} = 0mA	-	-	35	mA
I_{CCSB1}	Power Down Power Supply Current	V_{CC} = Max, $\overline{E}$ ≥ V_{CC} − 0 2V	-	-	20	mA
		V_{IN} ≥ V_{CC} − 0 2V or V_{IN} ≤0 2V			100[5]	μA

1 Typical characteristics are at V_{CC} = 5V, T_A = 25°C
2 These are absolute values with respect to device ground and all overshoots due to system or tester noise are included
3 V_{IL} (Min) = −3 0V for pulse width ≤ 20ns
4 F_{MAX} = 1/t_{RC}
5 L version only

CAPACITANCE[1] (T_A = 25°C, f = 1.0MHz)

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
C_{IN}	Input Capacitance	V_{IN} = 0V	8	pF
$C_{I/O}$	Input/Output Capacitance	$V_{I/O}$ = 0V	10	pF

1 This parameter is guaranteed and not tested

DATA RETENTION CHARACTERISTICS (over the commercial operating range)

| SYMBOL	PARAMETER	TEST CONDITIONS	MIN.	TYP[1]	MAX[2]	UNITS
V_{DR}	V_{CC} for Data Retention	$\overline{E}$ ≥ V_{CC}− 0 2V, $\overline{G}$ ≥ V_{CC} − 0 2V, V_{IN} ≥ V_{CC}− 0.2V or V_{IN} ≤ 0 2V	2 0[4]	-	-	V
I_{CCDR}	Data Retention Current	$\overline{E}$ ≥ V_{CC}− 0 2V, $\overline{G}$ ≥ V_{CC} − 0 2V, V_{IN} ≥ V_{CC}− 0 2V or V_{IN} ≤ 0 2V	-	2	50[4]	μA
t_{CDR}	Chip Deselect to Data Retention Time	See Retention Waveform	0	-	-	ns
t_R	Operation Recovery Time		t_{RC}[3]	-	-	ns

1 V_{CC} = 2V, T_A = +25°C
2 V_{CC} = 3V
3 t_{RC} = Read Cycle Time
4 L Version Only

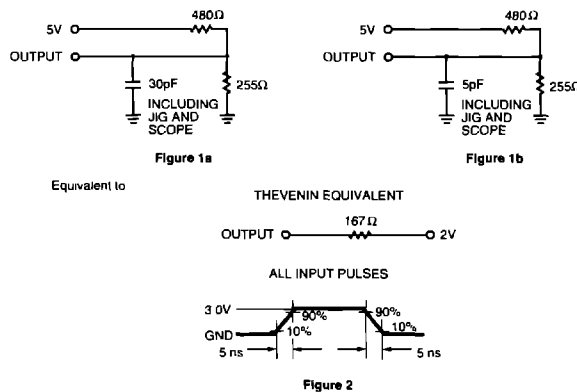## TIMING WAVEFORM LOW V_{CC} DATA RETENTION WAVEFORM
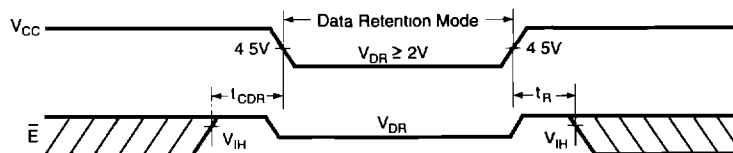
AC TEST CONDITIONS

Input Pulse Levels	0V to 3 0V
Input Rise and Fall Times	3ns
Timing Reference Level	1 5V

KEY TO SWITCHING WAVEFORMS

WAVEFORM	INPUTS	OUTPUTS
	MUST BE STEADY	WILL BE STEADY
	MAY CHANGE FROM H TO L	WILL BE CHANGING FROM H TO L
	MAY CHANGE FROM L TO H	WILL BE CHANGING FROM L TO H
	DON T CARE ANY CHANGE PERMITTED	CHANGING STATE UNKNOWN
	DOES NOT APPLY	CENTER LINE IS HIGH IMPEDANCE 'OFF' STATE

AC TEST LOADS AND WAVEFORMS

Figure 1a

Figure 1b

Equivalent to

THEVENIN EQUIVALENT

OUTPUT o—— 167 Ω ——o 2V

ALL INPUT PULSES

Figure 2

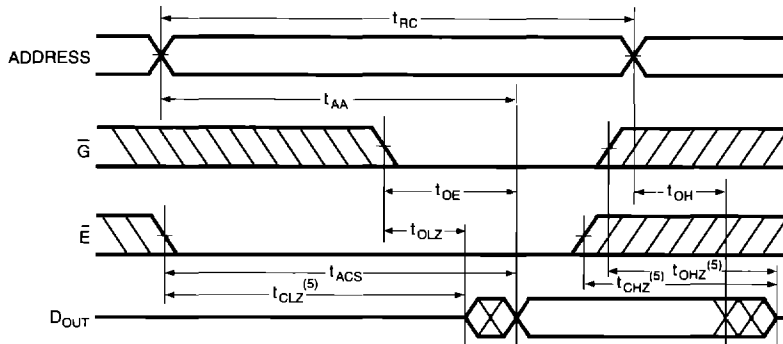## AC ELECTRICAL CHARACTERISTICS (over the commercial operating range)
READ CYCLE

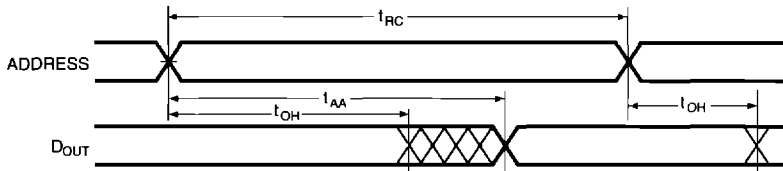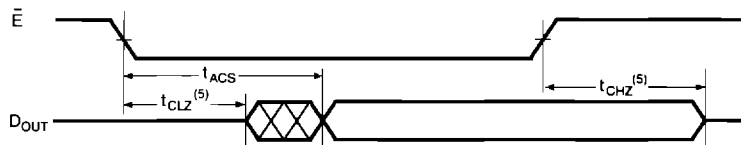| JEDEC PARAMETER NAME	PARAMETER NAME	PARAMETER	MS62256A-25		MS62256A-30		MS62256A-35		MS62256A-45		MS62256A-55		UNIT
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
t_{AVAX}	t_{RC}	Read Cycle Time	-	25	-	30	-	35	-	45	-	55	ns
t_{AVQV}	t_{AA}	Address Access Time	-	25	-	30	-	35	-	45	-	55	ns
t_{ELQV}	t_{ACS}	Chip Enable Access Time	-	25	-	30	-	35	-	45	-	55	ns
t_{GLQX}	t_{OE}	Output Enable to Output Valid	-	15	-	20	-	20	-	20	-	25	ns
t_{EHQZ}	t_{CLZ}	Chip Enable to Output Low Z	5	-	5	-	5	-	5	-	5	-	ns
t_{GLQX}	t_{OLZ}	Output Enable to Output in Low Z	0	-	0	-	0	-	0	-	0	-	ns
t_{EHQZ}	t_{CHZ}	Chip Disable to Output in High Z	-	15	-	20	-	20	-	20	0	25	ns
t_{GHQZ}	t_{OHZ}	Output Disable to Output in High Z	-	15	-	20	-	20	-	20	0	25	ns
t_{AXQX}	t_{OH}	Output Hold from Address Change	5	-	5	-	5	-	5	-	5	-	ns

MS62256A

SWITCHING WAVEFORMS (READ CYCLE)

READ CYCLE 1[1]

READ CYCLE 2[1, 2, 4]

READ CYCLE 3[1, 3, 4]

NOTES:
1. $\overline{W}$ is High for READ Cycle
2. Device is continuously selected $\overline{E} = V_{IL}$
3. Address valid prior to or coincident with $\overline{E}$ transition low
4. $\overline{G} = V_{IL}$
5. Transition is measured ± 500mV from steady state with C_L = 5pF as shown in Figure 1b This parameter is guaranteed and not 100% tested

## AC ELECTRICAL CHARACTERISTICS (over the commercial operating range)

WRITE CYCLE

| JEDEC PARAMETER NAME	PARAMETER NAME	PARAMETER	MS62256A-25		MS62256A-30		MS62256A-35		MS62256A-45		MS62256A-55		UNIT
			MIN.	MAX.	MIN.	MAX	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
t_{AVAX}	t_{WC}	Write Cycle Time	25	-	30	-	35	-	45	-	55	-	ns
t_{ELWH}	t_{CW}	Chip Enable to End of Write	20	-	25	-	30	-	40	-	50	-	ns
t_{AVWL}	t_{AS}	Address Set up Time	0	-	0	-	0	-	0	-	0	-	ns
t_{AVWH}	t_{AW}	Address Valid to End of Write	20	-	25	-	30	-	40	-	50	-	ns
t_{WLWH}	t_{WP}	Write Pulse Width	20	-	25	-	30	-	30	-	35	-	ns
t_{WHAX}	t_{WR}	Write Recovery Time	0	-	0	-	3	-	3	-	3	-	ns
t_{WLQZ}	t_{WHZ}	Write to Output in High Z	0	15	0	15	0	20	0	25	0	30	ns
t_{DVWH}	t_{DW}	Data to Write Time Overlap	15	-	15	-	20	-	20	-	25	-	ns
t_{WHDX}	t_{DH}	Data Hold from Write Time	0	-	0	-	0	-	0	-	0	-	ns
t_{GHQZ}	t_{OHZ}	Output Disable to Output in High Z	0	13	0	15	0	15	0	15	0	15	ns
t_{WHQX}	t_{OW}	Output Active from End of Write	5	-	5	-	5	-	5	-	5	-	ns

SWITCHING WAVEFORMS (WRITE CYCLE)

WRITE CYCLE 1[1]
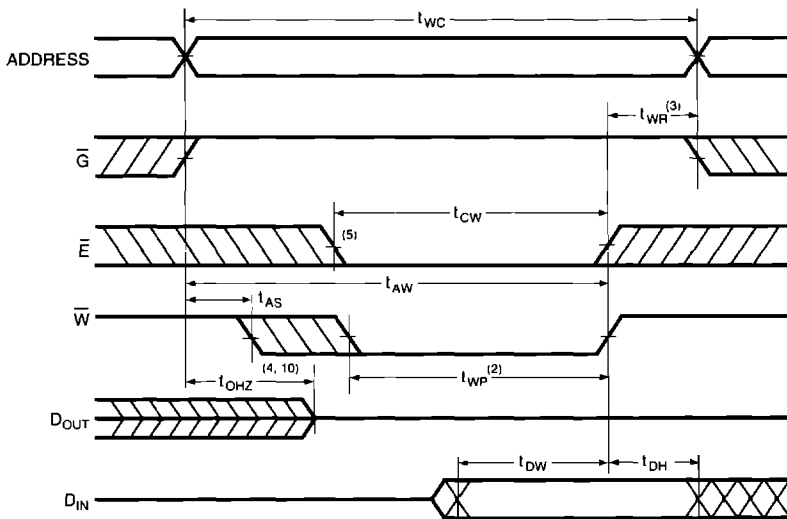
MS62256A

SWITCHING WAVEFORMS (WRITE CYCLE)

WRITE CYCLE 2[1,6]
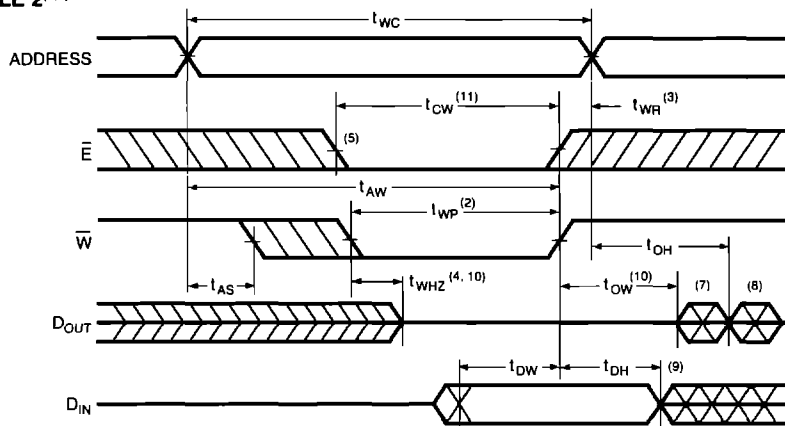
NOTES.
1. $\overline{W}$ must be high during address transitions
2. The internal write time of the memory is defined by the overlap $\overline{E}$ active and $\overline{W}$ low Both signals must be active to initiate and any one signal can terminate a write by going inactive The data input setup and hold timing should be referenced to the second transition edge of the signal that terminates the write
3. T_{WR} is measured from the earlier of $\overline{E}$ or $\overline{W}$ going high at the end of write cycle
4. During this period, DQ pins are in the output state so that the input signals of opposite phase to the outputs must not be applied
5. If the E low transition occurs simultaneously with the W low transitions or after the W low transition, outputs remain in a high impedance state
6. $\overline{G}$ is continuously low ($\overline{G} = V_{iL}$).
7. D_{OUT} is the same phase of write data of this write cycle
8. D_{OUT} is the read data of next address
9. If E is low during this period, DQ pins are in the output state Then the data input signals of opposite phase to the outputs must not be applied to them.
10. Transition is measured ±500mV from steady state with C_L = 5pF as shown in Figure 1b This parameter is guaranteed and not 100% tested
11. t_{CW} is measured from $\overline{E}$ going low to the end of write

ORDERING INFORMATION

SPEEDS	ORDERING PART NUMBER	PACKAGE REFERENCE NO.	TEMPERATURE RANGE
25	MS62256A-25PC	P28-1	0°C to +70°C
25	MS62256A-25NC	P28-2	0°C to +70°C
25	MS62256A-25RC	R28-1	0°C to +70°C
25	MS62256A-25SC	S28-6	0°C to +70°C
30	MS62256A-25PC	P28-1	0°C to +70°C
30	MS62256A-25NC	P28-2	0°C to +70°C
30	MS62256A-25RC	R28-1	0°C to +70°C
30	MS62256A-25SC	S28-6	0°C to +70°C
35	MS62256A-25PC	P28-1	0°C to +70°C
35	MS62256A-25NC	P28-2	0°C to +70°C
35	MS62256A-25RC	R28-1	0°C to +70°C
35	MS62256A-25SC	S28-6	0°C to +70°C
45	MS62256A-25PC	P28-1	0°C to +70°C
45	MS62256A-25NC	P28-2	0°C to +70°C
45	MS62256A-25RC	R28-1	0°C to +70°C
45	MS62256A-25SC	S28-6	0°C to +70°C
55	MS62256A-25PC	P28-1	0°C to +70°C
55	MS62256A-25NC	P28-2	0°C to +70°C
55	MS62256A-25RC	R28-1	0°C to +70°C
55	MS62256A-25SC	S28-6	0°C to +70°C

Note 1   For the low power part number, add an L after the "A" and before the "-" Example MS62256AL-25PC